Weak Magnetic Field Measurement with MTJ Sensor using Lock-in Amplification Technique

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Introduction - What is MTJ Sensor?

- MTJ: Magnetic Tunneling Junctions
- A non-magnetic layer sandwiched by two ferromagnetic layers called free layer and pinned layer



Transfer Curve



Measurement of Transfer Curve - Probe Station





The MTJ sensor on the chips



Image of a MTJ array

Noise Source in MTJ System

1. Johnson Noise:

$$S(f) = \frac{4Rhf}{e^{\frac{hf}{k_BT}} - 1} \approx 4Rk_BT \qquad \left(for \ f \ll \frac{k_BT}{h}\right)$$

2. Shot Noise:

$$S_I = 2eIR^2$$

3. Flicker Noise (1/f noise):

$$S_F(f) = \frac{\alpha V^2}{Af}$$

- α : Hooge parameter
- A : the junction area
- V : voltage across the sensor
- R : resistance across the sensor



Aim of the Project

Direct Measurement of Weak AC Magnetic Field (down to ~100pT) using Lock-in Amplification Technique.

Reproduce the Noise Voltage Spectrum in frequency domain

Lock-in Amplification Technique

Compare the reference waveform and the signal waveform

Lock the frequency and the phase of the signal

Powerful tools to eliminate background noise (e.g. Earth B-field)

Signal Recovery 7265 Dual Phase Lock-in Amplifier

Experimental Setup



Formula

►
$$B_{rms} = kI_{AC} = k \frac{V_{rms}}{R_1}$$
 (calibrated by LakeShore 450 Gaussmeter)

$$V_{LI} = V_{DC} \frac{R_0}{R_{MTJ} + R_0} \quad \Rightarrow \quad \Delta V_{LI} = V_{DC} \frac{R_0}{\left(R_{MTJ} + R_0\right)^2} \Delta R_{MTJ}$$

or
$$\Delta V_{LI} = V_{DC} \frac{R_0 R_{MTJ}}{(R_{MTJ} + R_0)^2} \gamma \Delta B$$
,

where γ is the sensitivity of the MTJ sensor.

► To have maximum ΔV_{LI} , we need $R_0 \approx R_{MTJ}$

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Lock-in
Amplifier
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or $\Delta V_{LI} = V_{DC} \frac{R_0 R_{MTJ}}{(R_{MTJ} + R_0)^2} \gamma \Delta B$,
where γ is the sensitivity of the MTJ sensor.
• To have maximum ΔV_{LI} , we need $R_0 \approx R_{MTJ}$



The metal box containing the small coil



The picture of the resistance R_0

Calibration Line of Small Coil



Result - In-phase Signal VS Magnetic Field (without external concentrator)



External Concentrator



The MTJ sensor with 2nd concentrator



The setup for large coil

Transfer Curve of the MTJ Sensor (with External Concentrator)



Calibration Line of Large Coil



Result - In-phase Signal VS Magnetic Field (with external concentrator)



Transfer Curve of the MTJ Sensor (with External Concentrator)



We need to add an offset Magnetic Field to get the maximum sensitivity!

Challenge: Small AC Magnetic Field $(\sim 1\mu A \text{ for } \sim 900pT)$ + Large DC Magnetic Field $(\sim 12\text{mA for } 0.104\text{mG})$



For impedance of coil << R_1 , R_2 $I_{coil} \approx I_{DC} + I_{osc}$

The coil circuit

Result - Signal VS Bias Voltage for Magnetic field



Experimental Setup 3





Result - In-phase Signal VS Magnetic Field (with external concentrator & Best B-field Offset)



Problem:

 $\sim 78 nV$ background noise appears when the AC voltage input for the coil is turned off.

It could come from the shot noise from the battery, but another measurement should be done to identify the source of the background noise.

Potential Problems 1

Unstable state at the most sensitivity region



Potential Problem 2

For small magnetic domain scan, the high sensitivity in large domain transfer curve cannot be reproduced.



Conclusion and Future Work

- Succeed to Measure 109pT AC Magnetic Field at 1000Hz Frequency.
- Future work:
 - 1.Continue the measurement at different frequency.
 - 2. Identify the source of the $\sim 78nV$ background noise.
 - 3.Use Helmholtz Coil to further investigate the potential problems.

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